Common Drain Amplifier or Source Follower

Figure 1(a) shows the source follower with ideal current source load. Figure 1(b) shows the ideal current source implemented by NMOS with constant gate to source voltage.

![Diagrams](image)

Figure 1. Common drain or source follower implementation.

1. Low Frequency Small Signal Equivalent Circuit

\[ V_1 = V_i, \quad V_2 = V_o, \quad V_{bs1} = -V_o, \quad V_{gs1} = V_i - V_o = V_1 - V_2 \]

\[ Y_L = g_{ds2} \text{ (or } Z_L = r_{ds2} \text{), } \quad Y_S = \infty \text{ (or } Z_S = 0) \]

From Figure 2(e),

\[ I_1 = 0 \]

\[ I_2 = -g_{m1} v_{gs1} + (g_{mb1} + g_{ds1}) V_o = -g_{m1} (V_1 - V_2) + (g_{mb1} + g_{ds1}) V_2 \]

\[ = -g_{m1} V_1 + (g_{m1} + g_{mb1} + g_{ds1}) V_2 \]
Figure 2. Source follower low frequency small signal equivalent circuit.
The corresponding Y-parameter matrix is,
\[
Y = \begin{bmatrix}
0 & 0 \\
-g_{m1} & g_{m1} + g_{mb1} + g_{ds1}
\end{bmatrix}
\]
\[
detY = 0
\]

The Source Follower Properties:

\[
Z_i = \frac{y_{22} + Y_L}{\detY + y_{11}Y_L} = \frac{(g_{m1} + g_{mb1} + g_{ds1}) + g_{ds2}}{0 + (0)g_{ds2}} = \infty
\]

\[
Z_o = \frac{y_{11} + Y_S}{\detY + y_{22}Y_S} = \frac{1}{y_{22}} = \frac{1}{g_{m1} + g_{mb1} + g_{ds1}}
\]

\[
A_{v0} = \frac{-y_{21}}{y_{22} + Y_L} = \frac{-(-g_{m1})}{(g_{m1} + g_{mb1} + g_{ds1}) + g_{ds2}} = \frac{g_{m1}}{g_{m1} + g_{mb1} + g_{ds1} + g_{ds2}} \approx 1
\]

Or

\[
A_v = g_{m1}(Z_o // Z_L)
\]

\[
A_l = \frac{-y_{21}Y_L}{\detY + y_{11}Y_L} = \frac{-g_{m1}g_{ds2}}{0 + (0)g_{ds2}} = \infty
\]
2. High Frequency Small Signal Equivalent Circuit

Figure 3 shows all the parasitic capacitances of source follower circuit. Figure 4 shows the high frequency small signal equivalent circuit. From Figure 4, one obtains,

\[ V_1^b = V_s, \quad V_2^b = V_i, \quad V_1^b = V_o, \quad V_{gs1}^b = V_1^b - V_2^b, \quad I_2^b = -I_1^b \]

\[ G_o = g_{mb1} + g_{ds1} + g_{ds2}, \quad C_o = C_{sb1} + C_{db2} + C_{gd2} + C_L \]

The network a current equation is:

\[ I_1^b = (G_s + sC_s)(V_1^b - V_2^b) \]

\[ I_2^b = (G_s + sC_s)(V_2^b - V_1^b) \]
Figure 4. Source follower high frequency small signal equivalent circuit.
The corresponding Y-parameter matrix is:

\[
Y^a = \begin{bmatrix}
(G_S + sC_S) & - (G_S + sC_S) \\
-(G_S + sC_S) & (G_S + sC_S)
\end{bmatrix}
\]

The network b current equation is:

\[
\begin{align*}
I^b_1 &= sC_{gdl}V^b_1 + sC_{gs1}(V^b_1 - V^b_2) = s(C_{gdl} + C_{gs1})V^b_1 - sC_{gs1}V^b_2 \\
I^b_2 &= -g_{ml}V_{gs1} + sC_{gs1}(V^b_2 - V^b_1) + (G_o + sC_o)V^b_2 = -g_{ml}(V^b_1 - V^b_2) + sC_{gs1}(V^b_2 - V^b_1) + (G_o + sC_o)V^b_2 \\
&= -(g_{ml} + sC_{gs1})V^b_1 + [g_{ml} + G_o + s(C_{gsl} + C_o)]V^b_2
\end{align*}
\]

The corresponding Y-parameter matrix is:

\[
Y^b = \begin{bmatrix}
s(C_{gdl} + C_{gs1}) & - sC_{gs1} \\
- (g_{ml} + sC_{gs1}) & g_{ml} + G_o + s(C_{gsl} + C_o)
\end{bmatrix}
\]

\[
\det Y^b = s(C_{gdl} + C_{gs1})[g_{ml} + G_o + s(C_{gsl} + C_o)] - sC_{gs1}(g_{ml} + sC_{gs1})
\]

\[
= sC_{gdl}[g_{ml} + G_o + s(C_{gsl} + C_o)] + sC_{gs1}(G_o + sC_o)
\]

The gain of network b, the unloaded last stage, is:

\[
A^b_V = \frac{V^b_2}{V^b_1} = \frac{-y^b_1}{y^b_2 + Y_L^b} = \frac{-y^b_2}{y^b_2} = \frac{g_{ml} + sC_{gs1}}{g_{ml} + G_o + s(C_{gsl} + C_o)}
\]

\[
Y_L^b = 0
\]

The input impedance of network b (or the load of network a) is given by:

\[
Z^b_i = \frac{y^b_2 + Y_L^b}{\det Y^b} = \frac{y^b_2}{\det Y^b} = \frac{g_{ml} + G_o + s(C_{gsl} + C_o)}{sC_{gdl}[g_{ml} + G_o + s(C_{gsl} + C_o)] + sC_{gs1}(G_o + sC_o)}
\]

The voltage gain of network a is given by:

\[
A^a_V = \frac{V^a_2}{V^a_1} = \frac{-y^a_1}{y^a_2 + Y_L^a} = \frac{1}{Z^b_i}
\]

\[
= \frac{G_S + sC_S}{G_S + sC_S + sC_{gdl}[g_{ml} + G_o + s(C_{gsl} + C_o)] + sC_{gs1}(G_o + sC_o)}
\]

\[
= \frac{G_S + sC_S}{(G_S + sC_S)(g_{ml} + G_o + s(C_{gsl} + C_o)) + sC_{gsl}[g_{ml} + G_o + s(C_{gsl} + C_o)] + sC_{gs1}(G_o + sC_o)}
\]

\[
= \frac{G_S + sC_S}{(G_S + sC_S)(g_{ml} + G_o + s(C_{gsl} + C_o)) + sC_{gsl}(G_o + sC_o)}
\]
The overall gain is given by:

\[
A_V = \frac{V_o}{V_S} = \frac{V_2}{V_1} = \left( \frac{V_2}{V_1} \right) \left( \frac{V_2^a}{V_1^a} \right) = A_V^b A_V^a \text{; since } V_1^b = V_2^a
\]

\[
= \frac{g_{m1} + sC_{gsl}}{g_{m1} + G_o + s(C_{gsl} + C_o)}
\]

\[
\begin{bmatrix}
(G_S + sC_s)[g_{m1} + G_o + s(C_{gsl} + C_o)] \\
(G_S + sC_s)[g_{m1} + G_o + s(C_{gsl} + C_o)] + sC_{gsl}[g_{m1} + G_o + s(C_{gsl} + C_o)] + sC_{gsl}(G_o + sC_o)
\end{bmatrix}
\]

\[
= \frac{(g_{m1} + sC_{gsl})(G_S + sC_s)}{[G_S + s(C_s + C_{gsl})][g_{m1} + G_o + s(C_{gsl} + C_o)] + sC_{gsl}(G_o + sC_o)}
\]

The trans-impedance of the overall network is:

\[
A_Z = \frac{V_o}{I_s} = \frac{V_o}{V_S(G_S + sC_S)} = -A_V
\]

\[
= \frac{g_{m1} + sC_{gsl}}{G_S(g_{m1} + G_o) + s[(C_S + C_{gsl})(g_{m1} + G_o) + G_S(C_{gsl} + C_o) + C_{gsl}G_o] + s^2[(C_S + C_{gsl})(C_{gsl} + C_o) + C_{gsl}C_o]}
\]

The DC gain is obtained by setting \( s=0 \).

\[
A_{Z0} = \frac{g_{m1}}{G_S(g_{m1} + G_o)}
\]

The transimpedance can be re-written as follows:

\[
A_{Z0}(1 + sC_{gsl})
\]

\[
A_Z = \frac{g_{m1}}{1 + bs + as^2}
\]

\[
b = \frac{(C_S + C_{gsl})(g_{m1} + G_o) + G_S(C_{gsl} + C_o) + C_{gsl}G_o}{G_S(g_{m1} + G_o)}
\]

\[
a = \frac{(C_S + C_{gsl})(C_{gsl} + C_o) + C_{gsl}C_o}{G_S(g_{m1} + G_o)}
\]
If the poles are far apart, their values can be estimated as follows:

\[ p_1 = -\frac{1}{b} = -\frac{G_S (g_{m1} + G_O)}{(C_S + C_{gd1})(g_{m1} + G_O) + G_S (C_{gs1} + C_O) + C_{gs1} G_O} \]

\[ p_2 = -\frac{a}{b} = -\frac{(C_S + C_{gd1})(g_{m1} + G_O) + G_S (C_{gs1} + C_O) + C_{gs1} G_O}{(C_S + C_{gd1})(C_{gs1} + C_O) + C_{gs1} C_O} \]

\[ z = -\frac{g_{m1}}{C_{gs1}} \]

The bandwidth and gain bandwidth product are defined by the dominant pole \( p_1 \). That is,

\[ w_{BW} = p_1 \]

\[ f_{BW} = \frac{w_{BW}}{2\pi} \]

\[ w_{GBW} = A_{z0} w_{BW} \]

\[ f_{GBW} = \frac{w_{GBW}}{2\pi} \]

The phase margin PM for non-inverting amplifier is the distance between the phase angle at the unity gain bandwidth frequency with respect to −180. For the source follower transfer function this is calculated as follows:

\[ A_Z(s) = \frac{A_{z0} (1 + \frac{s}{z})}{(1 + \frac{s}{p_1})(1 + \frac{s}{p_2})} \]

\[ A_Z(jw_{GBW}) = A_{z0} \frac{(1 + \frac{jw_{GBW}}{z})}{(1 + \frac{jw_{GBW}}{p_1})(1 + \frac{jw_{GBW}}{p_2})} \approx A_{z0} \frac{z}{(1 + \frac{jw_{GBW}}{p_1})(1 + \frac{jw_{GBW}}{p_2})} ; \text{ since } w_{GBW} >> p_1 \]

\[ \angle A_Z(jw_{GBW}) = \angle A_{z0} + \angle(1 + \frac{jw_{GBW}}{z}) - \angle(\frac{jw_{GBW}}{p_1}) - \angle(1 + \frac{jw_{GBW}}{p_2}) \]

\[ = 0 + \tan^{-1}\left(\frac{w_{GBW}}{z}\right) - 90 - \tan^{-1}\left(\frac{w_{GBW}}{p_2}\right) = -180 + PM \]

\[ PM = 90 + \tan^{-1}\left(\frac{w_{GBW}}{z}\right) - \tan^{-1}\left(\frac{w_{GBW}}{p_2}\right) \]
3. Source Follower as DC Level Shifter

We assume the source follower is operating at saturation mode. That is the drain current is given by:

\[ I_{DS} = \left( \frac{\beta}{2} \right) (V_{GS} - V_T)^2, V_{DS} > (V_{GS} - V_T) \]

where:

\[ \beta = K(W/L) \]

Therefore,

\[ V_{GS} - V_T = \sqrt{\frac{2I_{DS}}{\beta}} \]

or

\[ V_{GS} = V_T + \sqrt{\frac{2I_{DS}}{\beta}} \]

\[ V_{GS} = V_{in} - V_o = V_T + \sqrt{\frac{2I_{DS}}{\beta}} \]

If \( V_{BS} = 0 \), this is not possible for NMOS transistor in Nwell process.

\[ V_{GS} = V_{in} - V_o = -V_o + \sqrt{\frac{2I_{DS}}{\beta}} \]

This difference between the voltage level of the input and output can be specified by controlling \( W/L \) ratio for a given \( K \) and \( I_{DS} \).

In Figure 1(b), \( V_{BS} = -V_o \). Hence,

\[ V_{GS} = V_{in} - V_o = V_{TO} + \gamma(\sqrt{\phi} + V_o - \sqrt{\phi}) + \sqrt{\frac{2I_{DS}}{\beta}} \]

Note \( V_o \) appears on both sides of the equation, need iteration to determine the solution.

Common Drain Amplifier or Source Follower Experiments

4. Source Follower as DC Level Shifter

Source follower is a voltage follower, its gain is less than 1. The DC transfer characteristic has a slope of less than 1. First let us determine the maximum output voltage. For source follower this occurs when the input voltage \( V_{in} \) is at maximum or equal to \( V_{DD} \).

\[ V_{O(max)} = V_{DD} - V_T = V_{DD} - [V_{TO} + \gamma(\sqrt{\phi} + V_{O(max)} - \sqrt{\phi})] \]

\[ V_{O(max)} = 5 - [1 + 1(\sqrt{0.6} + V_{O(max)} - \sqrt{0.6})] \]

\[ V_{O(max)} + \sqrt{0.6 + V_{O(max)}} - 3.26 = 0 \]
This a non-linear equation, its solution requires iteration. A MATLAB m file is created to solve this problem. A call to MATLAB fzero function is invoke to obtain the solution as shown below:

*MATLAB m file “srcf.m” stored in \MATLAB directory

function y=srcf(vo)
y=vo+sqrt(0.6+vo)-3.26

*MATLAB “fzero” function invocation
vo=fzero(‘srcf’,1)
vo=1.7327

Pspice Vo(max)=1.7595

One can estimate the required bias of M1, using the biasing principle. The transistor M2 is a current sink biased to generate 100uA with a fixed gate to source voltage of $V_{GS}=V_{T0}+\Delta V=1+1.5=2.5$. That is the output voltage $V_o=\Delta V=1.5$. Since M1 and M2 are connected in series, means their current are the same. With both transistor have the same W/L means that the gate to source must be equal to $V_{T}+\Delta V$. But $V_T$ for transistor M1 is equal to $V_{TN}$ accounting for the non-zero bulk bias.

$$V_{BS} = -V_{O} = -1.5$$

$$V_{TN} = V_{T0} + \gamma(\frac{1}{\phi} - \frac{1}{V_{BS}} - \frac{1}{\phi}) = 1 + 1\left(\sqrt{0.6} - (-1.5) - \frac{1}{\sqrt{0.6}}\right) = 1.6745$$

$$V_{bias} = V_{O} + V_{TN} + \Delta V = 1.5 + 1.6745 + 1.5 = 4.6745$$

Due to gradual slope of the voltage DC transfer characteristic, it is difficult to obtain the proper operating point from Pspice simulation. To help on the bias determination the current DC transfer characteristic is also plotted for transistor M1. We know the bias current was designed for 100 uA. From Pspice simulation DC transfer characteristic, the bias voltage is 4.75V at $I_{DSQ}$=101.205uA. This is very closed to the theoretically calculated value.

Pspice netlist at this operating is simulated to obtain the small signal characteristics. The theoretical small signal parameters are determined and compared with Pspice simulation results.
\[ \beta_N = K_N \left( \frac{W}{L} \right)_N = (40 \cdot 10^{-6}) \left( \frac{9.6 \cdot 10^{-6}}{(5.4 - 1) \cdot 10^{-6}} \right) = 87.3 \cdot 10^{-6} \]

\[ I_{DSQ} = I_2 = \left( \frac{\beta_N}{2} \right) (V_{GSN} - V_{TO})^2 = \left( \frac{87.27 \cdot 10^{-6}}{2} \right) (25 - 1)^2 = 98.21 \mu A \]

\[ g_{m1} = g_{mN} = \sqrt{2\beta_N I_{DSQ}} = \sqrt{2(87.3 \cdot 10^{-6})(98.21 \cdot 10^{-6})} = 130.95 \mu mho \]

\[ g_{mb1} = \frac{\gamma}{2 \sqrt{\phi - V_{BS}}} g_{m1} = \frac{1}{2 \sqrt{0.6 - (-1.5)}} (130.95 \cdot 10^{-6}) = 45.18 \mu mho \]

\[ r_{ds1} = \frac{1}{\lambda_N I_{DSQ}} = \frac{1}{(0.02)(98.21 \cdot 10^{-6})} = .509 \Omega \]

\[ g_{ds1} = \frac{1}{r_{ds1}} = 1.9642 \cdot 10^{-6} \]

\[ r_{ds2} = \frac{1}{\lambda_P I_{DSQ}} = \frac{1}{(0.02)(98.21 \cdot 10^{-6})} = .509 \Omega \]

\[ g_{ds2} = \frac{1}{r_{ds2}} = 1.9642 \cdot 10^{-6} \]

\[ Z_0 = \frac{1}{g_{m1} + g_{mb1} + g_{ds1}} = \frac{1}{(130.95 + 45.18 + 1.9642) \cdot 10^{-6}} = 5.6 \Omega \]

\[ Z_i = \infty \]

\[ A_{V0} = \frac{g_{m1}}{g_{m1} + g_{mb1} + g_{ds1} + g_{ds2}} = \frac{130.95 \cdot 10^{-6}}{(130.95 + 45.18 + 1.9642 + 1.9642) \cdot 10^{-6}} = 0.73 \]

Comparing with Pspice results of:

\[ Z_i = 1 \cdot 10^{20} = \infty \]

\[ Z_o = 5.323 \Omega \]

\[ A_{V0} = .7315 \]

*Pspice file for NMOS Inverter with PMOS Current Load
*Filename="Lab3.cir"
VIN 1 0 DC 4.75VOLT AC 1V
VDD 3 0 DC 5VOLT
VSS 4 0 DC 0VOLT
VG2 5 0 DC 2.5VOLT
M1 3 1 2 4 MN W=9.6U L=5.4U
M2 2 5 4 4 MN W=9.6U L=5.4U
.MODEL MN NMOS VTO=1 KP=40U
+ GAMMA=1.0 LAMBDA=0.02 PHI=0.6
+ TOX=0.05U LD=0.5U CJ=5E-4 CJSW=10E-10
+ U0=550 MJ=0.5 MJSW=0.5 CGSO=0.4E-9 CGDO=0.4E-9
.MODEL MP PMOS VTO=-1 KP=15U
+ GAMMA=0.6 LAMBDA=0.02 PHI=0.6
+ TOX=0.05U LD=0.5U CJ=5E-4 CJSW=10E-10
+ U0=200 MJ=0.5 MJSW=0.5 CGSO=0.4E-9 CGDO=0.4E-9
*Analysis
.DC VIN 0 5 0.05
.TF V(2) VIN
.AC DEC 100 1HZ 10GHZ
.PROBE
.END

** SMALL-SIGNAL CHARACTERISTICS

V(2)/VIN = 7.315E-01
INPUT RESISTANCE AT VIN = 1.000E+20
OUTPUT RESISTANCE AT V(2) = 5.323E+03
5. Current Source Driven Source Follower As Transimpedance Amplifier

The voltage gain transfer function has two-zero at the LHP and two-pole at the LHP. That is phase plot is expected to cancel each other. Hence the dynamic range of the phase angle is small, hence large phase margin. The gain plot is below 0 db. That is determination of \( f_{\text{BW}} \) and \( f_{\text{GBW}} \) is not possible. Source follower does not have a voltage gain but has a transimpedance gain or voltage to current gain. The source follower is re-simulated using a current source input. The gain is highly dependent on the input impedance \( R_s \). The biasing current is determined to establish the same bias as in the voltage source. That is the bias current and input impedance \( R_s \) must be selected to produce a bias of 4.75V. This can be achieved by a current bias of 100uA and \( R_s \) of 0.0475Meg. The PSpice netlist with this bias is shown below:

*PSpice file for NMOS Inverter with PMOS Current Load
*Filename="Lab3a.cir"
IIN  0  1 DC 100u AC 1
VDD 3  0 DC 5VOLT
VSS 4  0 DC 0VOLT
VG2 5  0 DC 2.5VOLT
RS  1  0 0.0475Meg
M1 3  1 2 4 MN W=9.6U L=5.4U
M2 2  5 4 4 MN W=9.6U L=5.4U

.MODEL MN NMOS VTO=1 KP=40U
+ GAMMA=1.0 LAMBDA=0.02 PHI=0.6
+ TOX=0.05U LD=0.5U CJ=5E-4 CJSW=10E-10
+ U0=550 MJ=0.5 MJSW=0.5 CGSO=0.4E-9 CGDO=0.4E-9
.MODEL MP PMOS VTO=1 KP=15U
+ GAMMA=0.6 LAMBDA=0.02 PHI=0.6
+ TOX=0.05U LD=0.5U CJ=5E-4 CJSW=10E-10
+ U0=200 MJ=0.5 MJSW=0.5 CGSO=0.4E-9 CGDO=0.4E-9
*Analysis
*.DC VIN 0 5 0.05
.TF V(2) IIN
**6. Current Driven Source Follower High Frequency Model Experiments**

The parasitic capacitances will be determined to check the theory against Pspice simulation results. These capacitances will be determined at the operating point. The reverse biases are first calculated, using the node voltages at the operating point from Pspice simulation.

For M1,

\[
\begin{align*}
V_{DB} &= V(4) - V(3) = 0 - 5 = -5 \\
V_{BS} &= V(4) - V(2) = 0 - 1.5757 \\
\end{align*}
\]

For M2,

\[
\begin{align*}
V_{DB} &= V(4) - V(2) = 0 - 1.5757 = -1.5757 \\
V_{BS} &= 0 \\
\end{align*}
\]

The MATLAB program is invoked to obtain the parasitic capacitances.

For M1,

\[
\begin{align*}
\{C_{GS}, C_{GD}, C_{BD}, C_{BS}\} &= \text{CAP}(9.6, 5.4, -5, -1.5757) \\
C_{GS} &= 23.2704, \ C_{GD} = 3.84, \ C_{BD} = 15.6331, \ C_{BS} = 39.1607 \\
\end{align*}
\]

For M2,

\[
\begin{align*}
\{C_{GS}, C_{GD}, C_{BD}, C_{BS}\} &= \text{cap}(9.6, 5.4, -1.5757, 0) \\
C_{GS} &= 23.2704, \ C_{GD} = 3.84, \ C_{BD} = 25.0807, \ C_{BS} = 61.84 \\
\end{align*}
\]

The small signal low frequency gain is

\[
G_o = g_{mb1} + g_{ds1} + g_{ds2} = (45.18 + 1.9642 + 1.9642)E - 6 = 49.1084E - 6
\]

\[
A_{Z0} = \frac{g_{m1}}{G_s (g_{m1} + G_o)} = \frac{R_s g_{m1}}{(g_{m1} + G_o)} = \frac{(0.0475E6)(130.95E - 6)}{(130.95 + 49.1084)E - 6} = 34.5K \text{ or } 90.6\text{db}
\]
Pspice simulation result is $A_{zo} = 90.818$ db.

In this experiment, only $C_{gs}$ and $C_{gd}$ will be included in the simulation. Also, $C_s = C_L = 0$.

$$C_O = C_{sb} + C_{db} + C_{gd} + C_L = C_{gd} = 3.84 \text{fF}$$

$$(C_s + C_{gd})(g_{m1} + G_O) = ((0 + 3.84)E - 15)((130.95 + 49.1084)E - 6) = 691.42E - 21$$

$$G_S(C_{gs1} + C_O) = (21.05E - 6)((23.2704 + 3.84)E - 15) = 570.67E - 21$$

$$C_{gs1} G_O = (23.2704 E - 15)(49.1084E - 6) = 1142.77E - 21$$

$$p_1 = -\frac{G_S(g_{m1} + G_O)}{(C_s + C_{gd})(g_{m1} + G_O) + G_S(C_{gs1} + C_O) + C_{gs1} G_O}$$

$$= -\frac{(21.05E - 6)(130.95 + 49.1084)E - 6}{691.42E - 21 + 570.67E - 21 + 1142.77E - 21} = 1.576 \text{G}$$

$$p_2 = -\frac{(C_s + C_{gd})(g_{m1} + G_O) + G_S(C_{gs1} + C_O) + C_{gs1} G_O}{(C_s + C_{gd})(C_{gs1} + C_O) + C_{gs1} C_O}$$

$$= -\frac{(0 + 3.84)(23.2704 + 3.84)E - 30 + (23.2704)(3.84)E - 30}{691.42E - 21 + 570.67E - 21 + 1142.77E - 21} = 12.43 \text{E9}$$

$$z = -\frac{g_{m1}}{C_{gs1}} = -\frac{130.95E - 6}{23.2704E - 15} = 5.63 \text{E9}$$

$$f_Z = \frac{z}{2\pi} = \frac{5.63 \text{E9}}{2\pi} = 0.896 \text{G}$$

$$f_{BW} = \frac{p_1}{2\pi} = \frac{1.576 \text{E9}}{2\pi} = 250 \text{M}$$

$$w_{GBW} = A_{zo} p_1 = (34.5 \text{E3})(1.576 \text{E9}) = 54.372 \text{E12} = 54.372 \text{T}$$

$$f_{GBW} = \frac{w_{GBW}}{2\pi} = 8.65 \text{T}$$

$$PM = 90 + \tan^{-1}\left(\frac{w_{GBW}}{z}\right) - \tan^{-1}\left(\frac{w_{GBW}}{p_2}\right) = 90 + \tan^{-1}\left(\frac{54.372 \text{E12}}{5.63 \text{E9}}\right) - \tan^{-1}\left(\frac{54.372 \text{E12}}{12.43 \text{E9}}\right)$$

$$= 90 + 89.994 - 89.987 = 90.007$$
The Pspice simulation results are:

\[ f_{\text{BW}} = 268.225\text{M} \]
\[ f_{\text{GBW}} = 8.25\text{T} \]
\[ \text{PM} = 90.001 \]